

# FAMILY OF LOW-POWER WIDE BANDWIDTH SINGLE SUPPLY OPERATIONAL AMPLIFIERS WITH AND WITHOUT SHUTDOWN

#### **FEATURES**

- Rail-To-Rail Output
- V<sub>ICR</sub> Includes Ground
- Gain-Bandwidth Product . . . 9 MHz
- Supply Current . . . 730 μA/Channel
- Single, Duals, and Quad Versions
- Ultralow Power Down Mode I<sub>DD(SHDN</sub>) = 4 μA/Channel
- Specified Temperature Range

   -40°C to 125°C . . . Industrial Grade
- Supply Voltage Range . . . 2.7 V to 5.5 V
- Ultrasmall Packaging
   5 or 6 Pin SOT-23 (TLV2630/1)
   8 or 10 Pin MSOP (TLV2632/3)
- Universal Op-Amp EVM (See SLOU060 for More Information)

**Operational Amplifier** 



#### DESCRIPTION

The TLV263x single supply operational amplifiers provide rail-to-rail output with an input range that includes ground. The TLV263x takes the minimum operating supply voltage down to 2.7 V over the extended industrial temperature range (–40°C to 125°C) while adding the rail-to-rail output swing feature. The TLV263x also provides a 9 MHz gain-bandwidth product from only 730  $\mu\text{A}$  of supply current. The maximum recommended supply voltage is 5.5 V, which, when coupled with a 2.7-V minimum, allows the devices to be operated from lithium ion cells.

The combination of wide bandwidth, low noise, and low distortion makes it ideal for high speed and high resolution data converter applications. The ground input range allows it to directly interface to ground rail referred systems.

All members are available in PDIP and SOIC with the singles in the small SOT-23 package, duals in the MSOP, and quads in the TSSOP package.

The 2.7-V operation makes it compatible with Li-Ion powered systems and the operating supply voltage range of many micro-power microcontrollers available today including TI's MSP430.

#### AMPLIFIER SELECTION TABLE

DEVICE	V <sub>DD</sub> [V]	I <sub>DD</sub> /ch [μΑ]	V <sub>ICR</sub> [V]	GBW [MHz]	SLEW RATE [V/μs]	V <sub>n,</sub> 1 <u>kH</u> z [nV/√Hz]	lO [mA]
OPAx343	2.5-5.5	850	$-0.3$ to $V_{DD} + 0.3$	5.5	6	25	40
OPAx743	3.5–12	1100	-0.1 to V <sub>DD</sub> + 0.1	7	10	30	20
TLV278x	1.8–3.6	650	$-0.2$ to $V_{DD} + 0.2$	8	5	9	10
TLV263x	2.7-5.5	730	GND to V <sub>DD</sub> – 1	9	9.5	50	28
TLV262x	2.7-5.5	750	1 V to V <sub>DD</sub> + 0.2	11	10	27	28
OPAx353	2.7-5.5	8000	-0.1 to V <sub>DD</sub> + 0.1	44	22	7	40



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



### PACKAGE/ORDERING INFORMATION(1)

PRODUCT	PACKAGE	PACKAGE CODE	SYMBOL	SPECIFIED TEMPERATURE RANGE	ORDER NUMBER	TRANSPORT MEDIA
Single with Shi	utdown					
TLV2630ID	SOIC-8	D	_		TLV2630ID TLV2630IDR	Tube Tape and Reel
TLV2630IDBV	SOT-23-6	DBV	VAYI	−40°C to 125°C	TLV2630IDBVR† TLV2630IDBVT‡	Tape and Reel
TLV2630IP	DIP-8	Р	_		TLV2630IP	Tube
Single without	Shutdown					
TLV2631ID	SOIC-8	D	_		TLV2631ID TLV2631IDR	Tube Tape and Reel
TLV2631IDBV	SOT-23-5	DBV	VAZI	−40°C to 125°C	TLV2631IDBVR <sup>†</sup> TLV2631IDBVT <sup>‡</sup>	Tape and Reel
TLV2631IP	DIP-8	Р	_		TLV2631IP	Tube
Dual without S	hutdown					
TLV2632ID	SOIC-8	D	_		TLV2632ID TLV2632IDR	Tube Tape and Reel
TLV2632IDGK	MSOP-8	DGK	AKG	−40°C to 125°C	TLV2632IDGK TLV2632IDGKR	Tube Tape and Reel
TLV2632IP	DIP-8	Р	_		TLV2632IP	Tube
Dual with Shut	down					
TLV2633ID	SOIC-14	D	1		TLV2633ID TLV2633IDR	Tube Tape and Reel
TLV2633IDGS	MSOP-10	DGS	AKK	−40°C to 125°C	TLV2633IDGS TLV2633IDGSR	Tube Tape and Reel
TLV2633IN	DIP-14	N	_		TLV2633IN	Tube
Quad without S	Shutdown					
TLV2634ID	SOIC-14	D	_		TLV2634ID TLV2634IDR	Tube Tape and Reel
TLV2634IN	DIP-14	N	_	-40°C to 125°C	TLV2634IN	Tube
TLV2634IPW	TSSOP-14	PW	_		TLV2634IPW TLV2634IPWR	Tube Tape and Reel
Quad with Shu	tdown					
TLV2635ID	SOIC-16	D	_		TLV2635ID TLV2635IDR	Tube Tape and Reel
TLV2635IN	DIP-16	N	_	-40°C to 125°C	TLV2635IN	Tube
TLV2635IPW	TSSOP-16	PW	_		TLV2635IPW TLV2635IPWR	Tube Tape and Reel

<sup>†</sup> The SOT23 package devices are only available taped and reeled. The R Suffix denotes quantities (3,000 pieces per reel).



<sup>&</sup>lt;sup>‡</sup> The **T** Suffix denotes smaller quantities (250 pieces per mini-reel).

<sup>1.</sup> For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

## absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V <sub>DD</sub> (see Note 1)	6 V
Differential input voltage, V <sub>ID</sub>	
Input voltage range, V <sub>I</sub> (see Note 1)	
Input current, I <sub>I</sub> (any input)	
Output current, IO	±40 mA
Continuous total power dissipation	
Operating free-air temperature range, T <sub>A</sub> : I-suffix	–40°C to 125°C
Maximum junction temperature, T <sub>J</sub>	150°C
Storage temperature range, T <sub>stq</sub>	65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

NOTE 2: All voltage values, except differential voltages, are with respect to GND.

## recommended operating conditions

		MIN	MAX	UNIT
Complex of the rest V	Single supply	2.7	5.5	
Supply voltage, V <sub>DD</sub>	Split supply	±1.35	±2.75	V
Common-mode input voltage range, VICR		GND	V <sub>DD</sub> -1	V
Operating free-air temperature, TA	I-suffix	-40	125	°C
Shutdown on/off voltage level‡	V <sub>IL</sub>		0.4	V
Silutuowii oli/oli voltage level+	ViH	2	_	V

<sup>‡</sup> Relative to GND.

# electrical characteristics at specified free-air temperature, $V_{DD} = 2.7 \text{ V}$ , 5 V (unless otherwise noted)

### dc performance

	PARAMETER	TEST CONDITION	ONS	TA	MIN	TYP	MAX	UNIT
			25°C		250	3500	.,	
				Full range			4500	μV
VIO	Input offset voltage	$V_{IC} = V_{DD}/2,$ $V_{O} = V_{DD}/2$	TIVOCOAIE	25°C		250	4200	/
		$V_O = V_{DD}/2$	TLV2634/5	Full range			5200	μV
αΛΙΟ	Temperature coefficient of input offset voltage			25°C		3		μV/°C
			V <sub>DD</sub> = 2.7 V	25°C	76	100		
CMDD	Common mode rejection ratio	\\\- CND to \/== 4 \/		Full range	67			dB
CMRR	Common-mode rejection ratio	$V_{IC} = GND \text{ to } V_{DD}-1 \text{ V}$	V 5.V	25°C	77	100		uБ
			$V_{DD} = 5 V$	Full range	74			
	Large-signal differential voltage			25°C	90	100		9
AVD	amplification	$R_L = 2 k\Omega$ , $V_{O(PP)} = V_D$	D-1 V	Full range	82			dB



<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## electrical characteristics at specified free-air temperature, $V_{DD}$ = 2.7 V, 5 V (unless otherwise noted) (continued)

## input characteristics

PARAMETER		TEST CONDITIONS	T <sub>A</sub> †	MIN	TYP	MAX	UNIT
	land affect account		25°C		1	50	
IO	Input offset current	$V_{IC} = V_{DD}/2,$	Full range			100	A
	Land bin a summer	$V_{IC} = V_{DD}/2,$ $V_{O} = V_{DD}/2$	25°C		1	50	pA
IB	Input bias current		Full range			200	
r <sub>i(d)</sub>	Differential input resistance		25°C		1000		GΩ
C <sub>i(c)</sub>	Common-mode input capacitance	f = 1 kHz	25°C		12		pF

<sup>†</sup> Full range is –40°C to 125°C for the I-suffix.

### output characteristics

	PARAMETER	TEST CONDITION	NS	T <sub>A</sub> †	MIN	TYP	MAX	UNIT	
			\/ 0.7.\/	25°C	2.6	2.67			
		V V (0 1 4 mA	$V_{DD} = 2.7 V$	Full range	2.55				
		$V_{IC} = V_{DD}/2$ , $I_{OH} = -1 \text{ mA}$	.,	25°C	4.92	4.98			
V	Hab laval autout valtage		$V_{DD} = 5 V$	Full range	4.9			V	
VOH High-level output voltage		\/ 0.7./	25°C	2.25	2.43		V		
		V:- V/2	$V_{DD} = 2.7 V$	Full range	2.15				
		$V_{IC} = V_{DD}/2$ , $I_{OH} = -10 \text{ mA}$	\/ <b>5</b> \/	25°C	4.7	4.8			
			$V_{DD} = 5 V$	Full range	4.65				
		\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\	\/ 27\/	25°C		0.03	0.1	mV	
	Law law law a subset walkana		$V_{DD} = 2.7 V$	Full range			0.15		
		$V_{IC} = V_{DD}/2$ , $I_{OL} = 1 \text{ mA}$	Vpp - 5 V	25°C		0.025	0.08		
V			$V_{DD} = 5 V$	Full range			0.1		
VOL	Low-level output voltage	$V_{IC} = V_{DD}/2$ , $I_{OL} = 10 \text{ mA}$	\/ 27\/	25°C		0.26	0.45		
			$V_{DD} = 2.7 V$	Full range			0.47		
			V 5.V	25°C		0.2	0.3		
			$V_{DD} = 5 V$	Full range			0.35		
		V <sub>DD</sub> = 2.7 V,	Sourcing			14			
1-	Output oursent	$V_O = 0.5 \text{ V from rail}$	Sinking	25°C		19		A	
IO	Output current	V <sub>DD</sub> = 5 V,	Sourcing	25°C		28		mA	
		V <sub>O</sub> = 0.5 V from rail	Sinking			28			
		Sourcing	$V_{DD} = 2.7 V$			50			
loo	Chart airquit autaut aurrant	Sourcing	V <sub>DD</sub> = 5 V	25°C		95		m 1	
los :	Short-circuit output current	Cinking	$V_{DD} = 2.7 \text{ V}$	25.0		50		mA	
		Sinking	V <sub>DD</sub> = 5 V			95			

<sup>†</sup> Full range is –40°C to 125°C for the I-suffix.

### power supply

PARAMETER		TEST CONDITIONS		T <sub>A</sub> †	MIN	TYP	MAX	UNIT
	0 1 1/ 1 1	., ,, ,,	OUDN V	25°C		730	1000	
IDD	Supply current (per channel)	$V_O = V_{DD}/2$ ,	SHDN = V <sub>DD</sub>	Full range			1350	μΑ
DCDD	Supply voltage rejection ratio	$V_{DD} = 2.7 \text{ V to } 5.5 \text{ V},$	Natard	25°C	70	90		4D
PSRR	$(\Delta V_{DD} / \Delta V_{IO})$	$V_{IC} = V_{DD}/2$	No load	Full range	65			dB

<sup>†</sup> Full range is –40°C to 125°C for the I-suffix.



## electrical characteristics at specified free-air temperature, $V_{DD}$ = 2.7 V, 5 V (unless otherwise noted) (continued)

### dynamic performance

	PARAMETER TEST CONDIT		TIONS	T <sub>A</sub> †	MIN	TYP	MAX	UNIT	
GBWP	Gain-bandwidth product	$R_L = 2 k\Omega$ , $C_L = 10 pF$ ,	f = 10 kHz			9		MHz	
		D 010 0 50 F	$V_{DD} = 2.7 \text{ V},$ $V_{O(PP)} = 1.7 \text{ V}$		6		\// -		
SR+ Positive slew rate	Positive slew rate at unity gain	$R_L = 2 k\Omega$ , $C_L = 50 pF$	$V_{DD} = 5 \text{ V},$ $V_{O(PP)} = 3.5 \text{ V}$			6		V/µs	
		D 010 0 50 F	$V_{DD} = 2.7 \text{ V},$ $V_{O(PP)} = 1.7 \text{ V}$	25°C		10		V/μs	
SR-	Negative slew rate at unity gain	$R_L = 2 k\Omega$ , $C_L = 50 pF$	V <sub>DD</sub> = 5 V, V <sub>O(PP)</sub> = 3.5 V			9.5		V/μs	
φm	Phase margin	<b>D</b> 010	0 40 - 5			50		0	
	Gain margin	$R_L = 2 k\Omega$ ,	$C_L = 10 pF$			20		dB	

<sup>†</sup> Full range is –40°C to 125°C for the I-suffix.

#### noise/distortion performance

PARAMETER		TEST CONDITIO	TEST CONDITIONS		MIN	TYP	MAX	UNIT	
			A <sub>V</sub> = 1		0.003%				
THD + N Total harmonic distortion plus noise		$V_{O(PP)} = V_{DD}/2,$ $R_1 = 2 k\Omega, f = 10 kHz$	A <sub>V</sub> = 10		0.02%				
			A <sub>V</sub> = 100	0500		0.095%			
	Emphysical interest parts and the ma	f = 1 kHz		25°C		50		nV/√ <del>Hz</del>	
V <sub>n</sub> Equivalent input noise voltage		f = 10 kHz				30		nv/√Hz	
In	Equivalent input noise current	f = 1 kHz				0.9		fA/√Hz	

#### shutdown characteristics

PARAMETER		TEST CONDITIONS		T <sub>A</sub> †	MIN	TYP	MAX	UNIT
1	Supply current, per channel in shutdown	SHDN = 0.4 V		25°C		4	17	^
IDD(SHDN)	mode (TLV2630, TLV2633, TLV2635)			Full range			19	μΑ
4	A many life out to the company time of		V <sub>DD</sub> = 2.7 V			4.5		
t(on)	Amplifier turnon time‡	$R_L = 2 k\Omega$ , $C_L = 10 pF$	V <sub>DD</sub> = 5 V	25°C		1.5		μs
t(off)	Amplifier turnoff time‡	о 10 рі				200		ns

<sup>†</sup> Full range is –40°C to 125°C for the I-suffix.



<sup>‡</sup> Disable time and enable time are defined as the interval between application of the logic signal to SHDN and the point at which the supply current has reached half its final value.

#### **DISSIPATION RATING TABLE**

PACKAGE	(°C/M) ⊕1C	<sup>⊝</sup> JA (°C/W)	$T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ POWER RATING	T <sub>A</sub> = 125°C POWER RATING
D (8)	38.3	176	710 mW	142 mW
D (14)	26.9	122.3	1022 mW	204.4 mW
D (16)	25.7	114.7	1090 mW	218 mW
DBV (5)	55	324.1	385 mW	77.1 mW
DBV (6)	55	294.3	425 mW	85 mW
DGK (8)	54.2	259.9	481 mW	96.1 mW
DGS (10)	54.1	259.7	485 mW	97 mW
N (14, 16)	32	78	1600 mW	320.5 mW
P (8)	41	104	1200 mW	240.4 mW
PW (14)	29.3	173.6	720 mW	144 mW
PW (16)	28.7	161.4	774 mW	154.9 mW

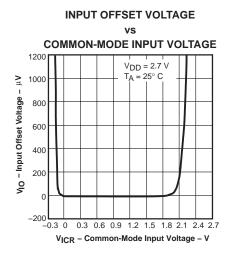
### **TYPICAL CHARACTERISTICS**

## **Table of Graphs**

			FIGURE
V <sub>IO</sub>	Input offset voltage	vs Common-mode input voltage	1, 2
CMRR	Common-mode rejection ratio	vs Frequency	3
Voн	High-level output voltage	vs High-level output current	4, 6
VOL	Low-level output voltage	vs Low-level output current	5, 7
l <sub>DD</sub>	Supply current	vs Supply voltage	8
l <sub>DD</sub>	Supply current	vs Free-air temperature	9
PSRR	Power supply rejection ratio	vs Frequency	10
$A_{VD}$	Differential voltage amplification & phase	vs Frequency	11
		vs Supply voltage	12
	Gain-bandwidth product	vs Free-air temperature	13
SR	Oleverate	vs Supply voltage	14
	Slew rate	vs Free-air temperature	15, 16
фm	Phase margin	vs Load capacitance	17
V <sub>n</sub>	Equivalent input noise voltage	vs Frequency	18
	Crosstalk	vs Frequency	19
	Voltage-follower large-signal pulse response		20
	Voltage-follower small-signal pulse response		21
IDD(SHDN)	Shutdown supply current	vs Free-air temperature	22
IDD(SHDN)	Shutdown supply current	vs Supply voltage	23
IDD(SHDN)	Shutdown supply current/output voltage	vs Time	24



**INPUT OFFSET VOLTAGE** 



COMMON-MODE INPUT VOLTAGE

1200

VDD = 5 V

TA = 25° C

98
800

400

-200

-0.5 0 0.5 1 1.5 2 2.5 3 3.5 4 4.5 5

VICR - Common-Mode Input Voltage - V

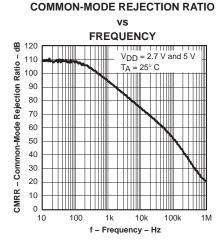
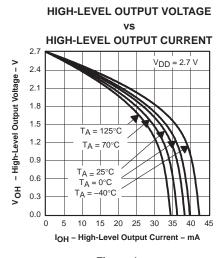


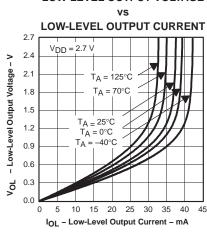
Figure 1

Figure 2

LOW-LEVEL OUTPUT VOLTAGE

Figure 3





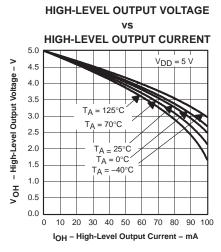
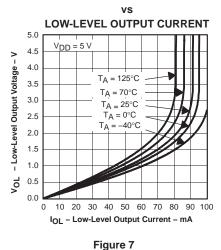


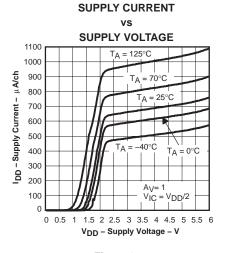
Figure 4

**LOW-LEVEL OUTPUT VOLTAGE** 

Figure 5

Figure 6





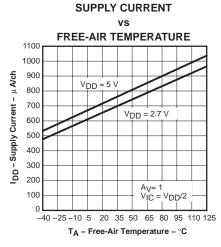


Figure 9

re 7 Figure 8



#### **POWER SUPPLY REJECTION RATIO**

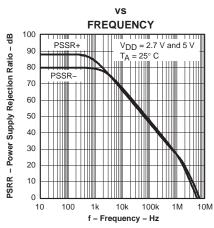


Figure 10

#### **DIFFERENTIAL VOLTAGE AMPLIFICATION AND PHASE**

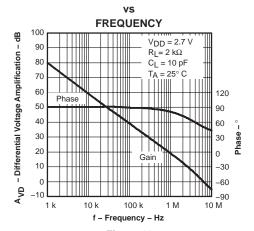


Figure 11

**GAIN-BANDWIDTH PRODUCT** 

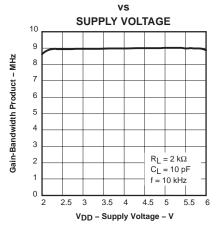
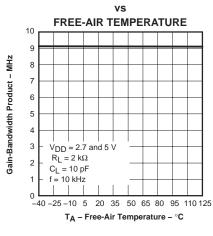


Figure 12



**GAIN-BANDWIDTH PRODUCT** 

Figure 13

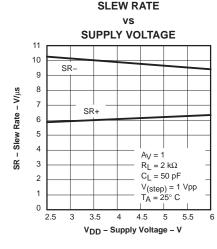


Figure 14

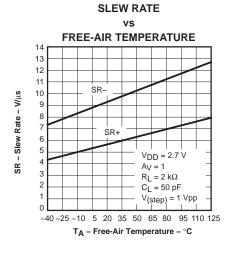


Figure 15

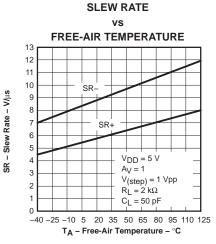


Figure 16

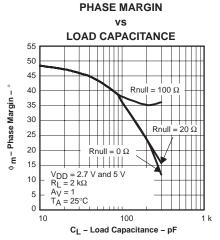


Figure 17



#### **EQUIVALENT INPUT NOISE VOLTAGE**

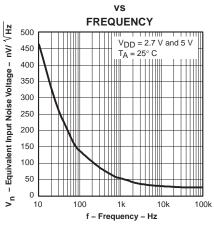


Figure 18

#### **VOLTAGE-FOLLOWER LARGE-SIGNAL**

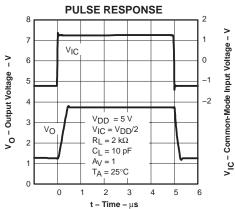


Figure 20

#### SHUTDOWN SUPPLY CURRENT

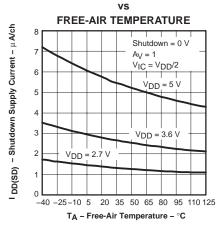


Figure 22

#### **FREQUENCY** $V_{DD} = 2.7 \text{ V}$ and 5 V $R_L = 2 \text{ k}\Omega$ -20 $C_L = 10 \text{ pF}$ $A_V = 1$ -40 VO(PP) = V<sub>DD</sub>/2 T<sub>A</sub> = 25°C -60 Crosstalk – All Channels -80

Shutdown Crosstall

100

-100

-120

-140

10

**CROSSTALK** 

vs

f - Frequency - Hz Figure 19

1k

Crosstalk

10k

100k

#### **VOLTAGE-FOLLOWER SMALL-SIGNAL**

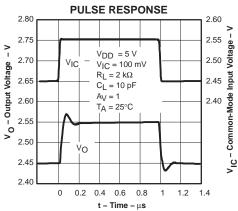


Figure 21

#### SHUTDOWN SUPPLY CURRENT

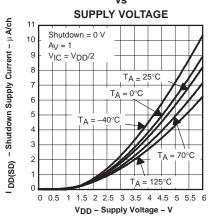
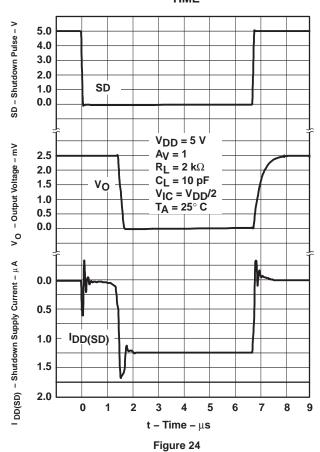


Figure 23

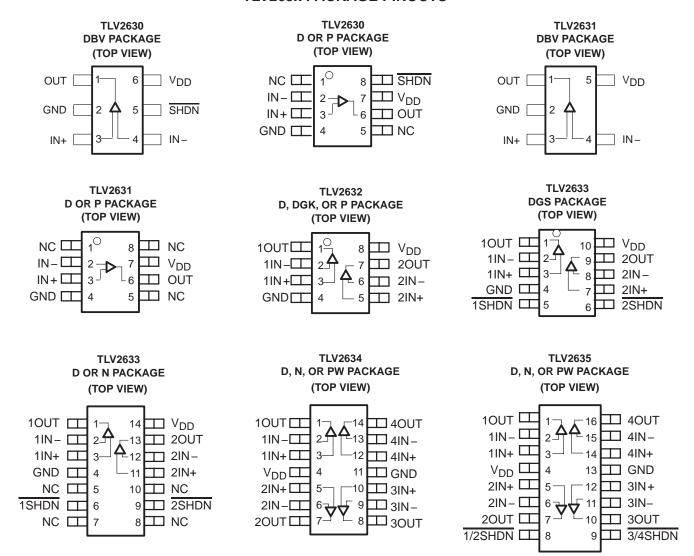


## SHUTDOWN SUPPLY CURRENT / OUTPUT VOLTAGE

TIME



#### **TLV263x PACKAGE PINOUTS**



NC - No internal connection





24-Aug-2014

#### **PACKAGING INFORMATION**

Orderable Device	Status	Package Type	Package	Pins	Package	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
	(1)		Drawing		Qty	(2)	(6)	(3)		(4/5)	
TLV2630IDBVR	ACTIVE	SOT-23	DBV	6	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VAYI	Samples
TLV2631IDBVR	ACTIVE	SOT-23	DBV	5	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VAZI	Samples
TLV2631IDBVT	ACTIVE	SOT-23	DBV	5	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	VAZI	Samples
TLV2632IDGKR	ACTIVE	VSSOP	DGK	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	AKG	Samples
TLV2632IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	26321	Samples
TLV2634ID	ACTIVE	SOIC	D	14	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	26341	Samples
TLV2634IPWR	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 125	26341	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.



### PACKAGE OPTION ADDENDUM

24-Aug-2014

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

(6) Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

## **PACKAGE MATERIALS INFORMATION**

www.ti.com 3-Aug-2017

## TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

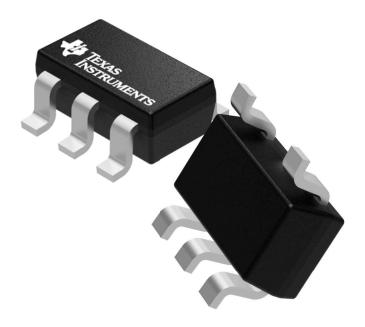
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLV2630IDBVR	SOT-23	DBV	6	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2631IDBVR	SOT-23	DBV	5	3000	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2631IDBVT	SOT-23	DBV	5	250	180.0	9.0	3.15	3.2	1.4	4.0	8.0	Q3
TLV2632IDGKR	VSSOP	DGK	8	2500	330.0	12.4	5.3	3.4	1.4	8.0	12.0	Q1
TLV2632IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TLV2634IPWR	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

www.ti.com 3-Aug-2017



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLV2630IDBVR	SOT-23	DBV	6	3000	182.0	182.0	20.0
TLV2631IDBVR	SOT-23	DBV	5	3000	182.0	182.0	20.0
TLV2631IDBVT	SOT-23	DBV	5	250	182.0	182.0	20.0
TLV2632IDGKR	VSSOP	DGK	8	2500	358.0	335.0	35.0
TLV2632IDR	SOIC	D	8	2500	340.5	338.1	20.6
TLV2634IPWR	TSSOP	PW	14	2000	367.0	367.0	35.0



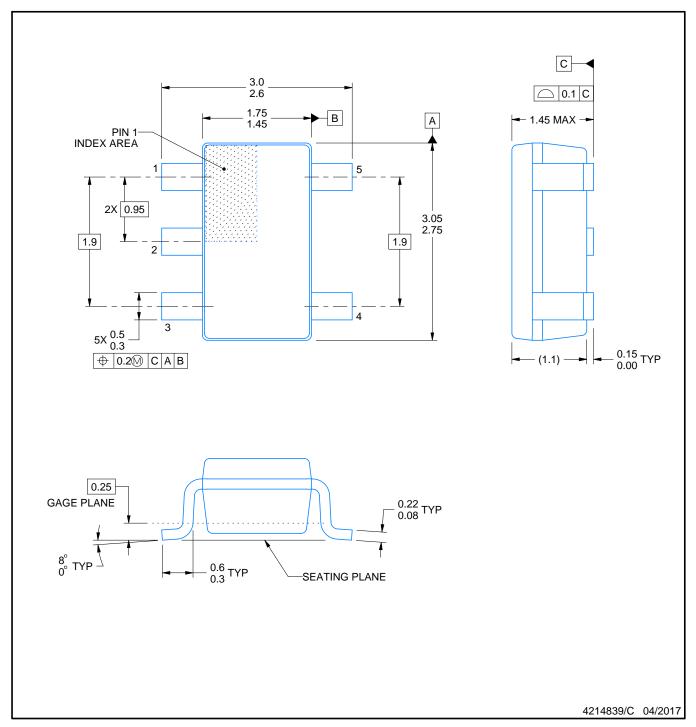
Images above are just a representation of the package family, actual package may vary. Refer to the product data sheet for package details.

4073253/P





SMALL OUTLINE TRANSISTOR



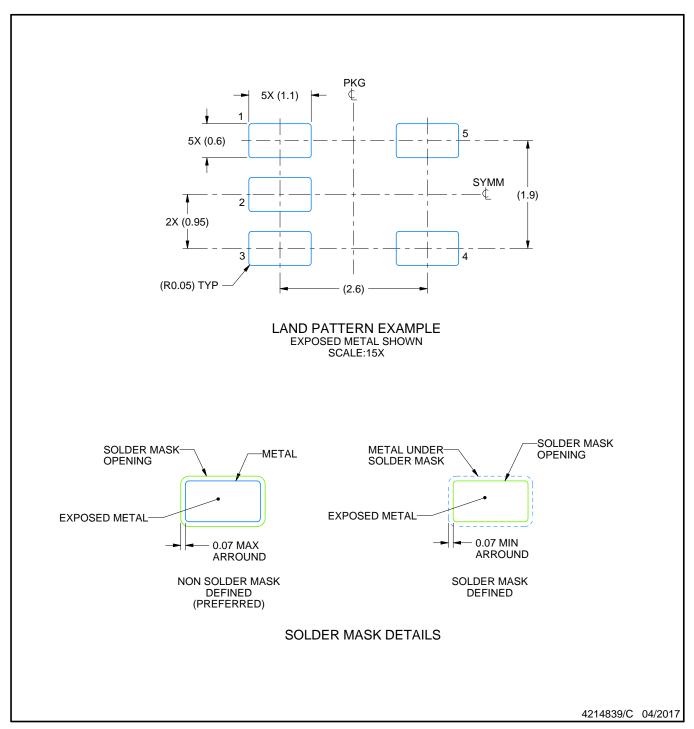
- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. Reference JEDEC MO-178.



SMALL OUTLINE TRANSISTOR

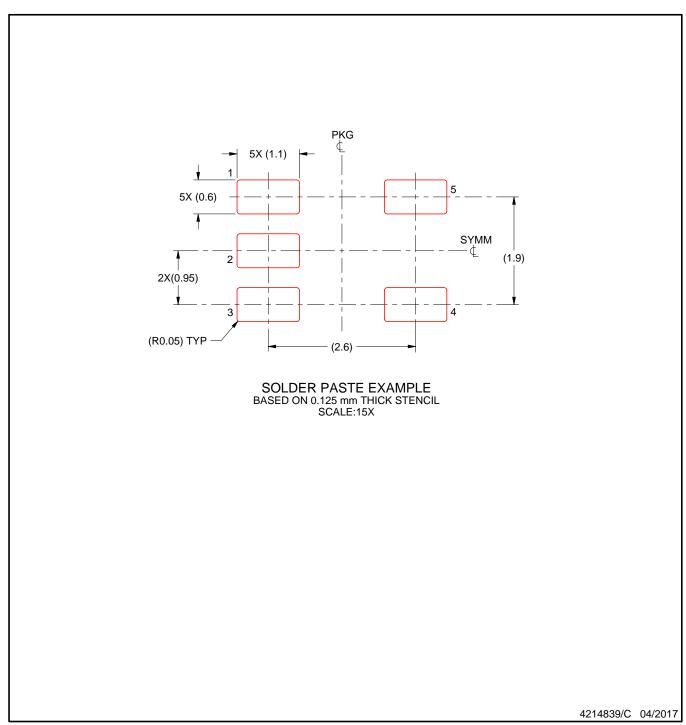


NOTES: (continued)

- 4. Publication IPC-7351 may have alternate designs.
- 5. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



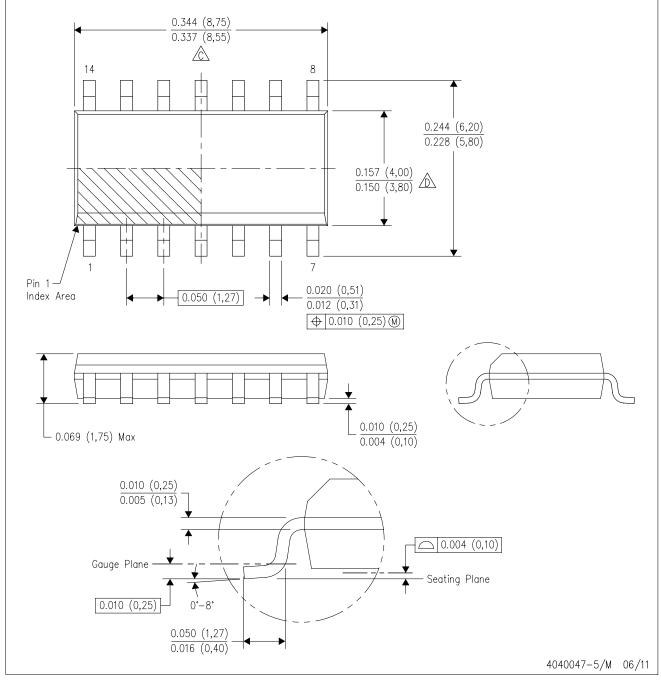
NOTES: (continued)

- 6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 7. Board assembly site may have different recommendations for stencil design.



## D (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



# D (R-PDSO-G14)

## PLASTIC SMALL OUTLINE

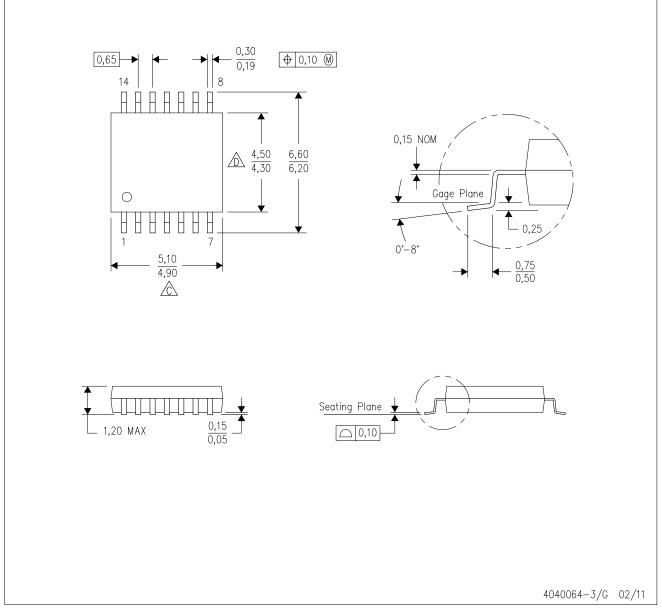


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G14)

## PLASTIC SMALL OUTLINE

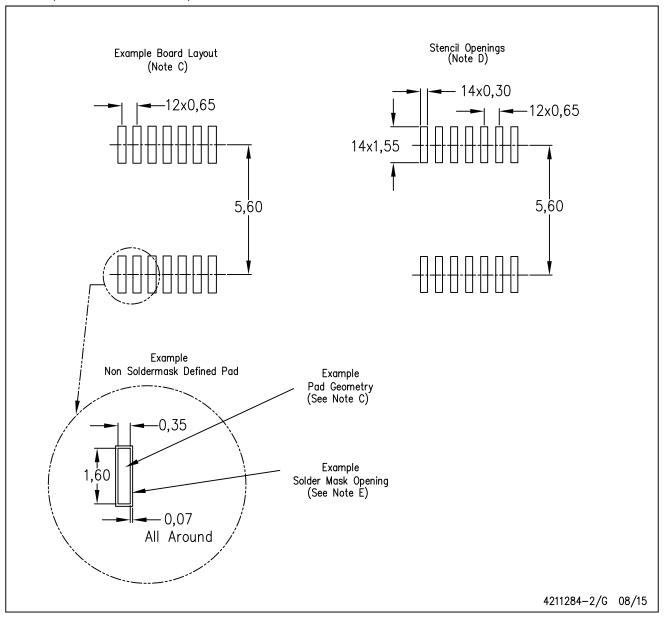


- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
  - Sody length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



# PW (R-PDSO-G14)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



## D (R-PDSO-G8)

## PLASTIC SMALL OUTLINE

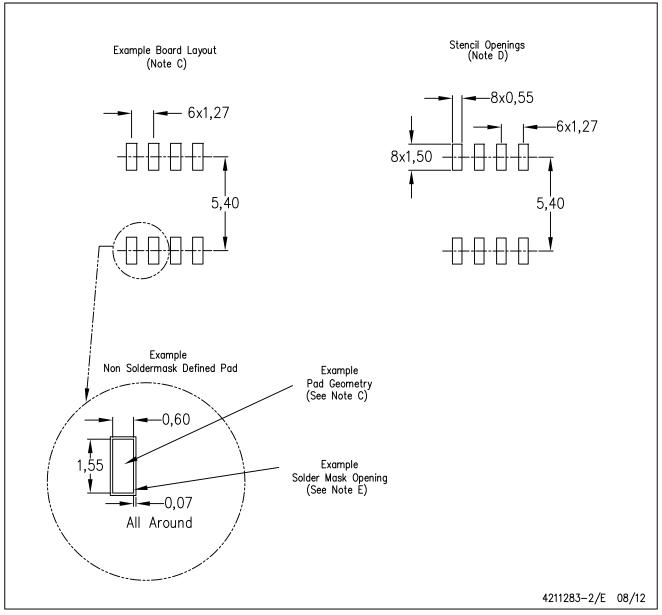


- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



# D (R-PDSO-G8)

# PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



# DGK (S-PDSO-G8)

# PLASTIC SMALL-OUTLINE PACKAGE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



# DBV (R-PDSO-G6)

## PLASTIC SMALL-OUTLINE PACKAGE

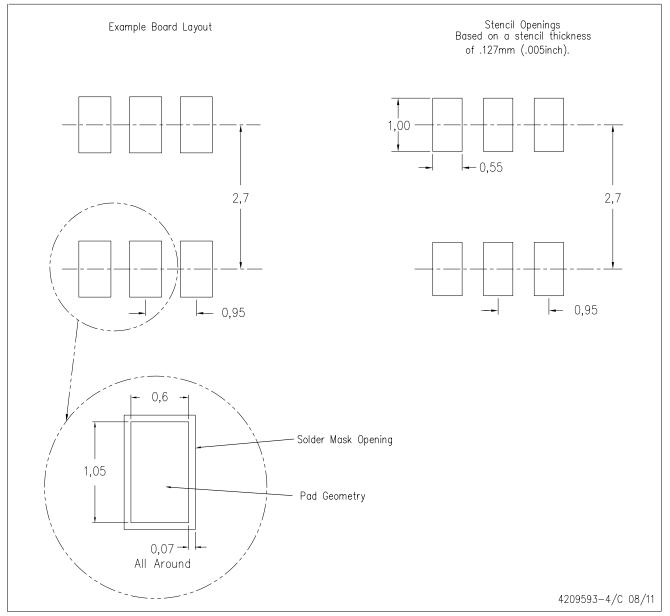


- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion. Mold flash and protrusion shall not exceed 0.15 per side.
- D. Leads 1,2,3 may be wider than leads 4,5,6 for package orientation.
- Falls within JEDEC MO-178 Variation AB, except minimum lead width.



# DBV (R-PDSO-G6)

## PLASTIC SMALL OUTLINE



- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. Publication IPC-7351 is recommended for alternate designs.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil recommendations.



#### **IMPORTANT NOTICE**

Texas Instruments Incorporated (TI) reserves the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete.

TI's published terms of sale for semiconductor products (http://www.ti.com/sc/docs/stdterms.htm) apply to the sale of packaged integrated circuit products that TI has qualified and released to market. Additional terms may apply to the use or sale of other types of TI products and services.

Reproduction of significant portions of TI information in TI data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such reproduced documentation. Information of third parties may be subject to additional restrictions. Resale of TI products or services with statements different from or beyond the parameters stated by TI for that product or service voids all express and any implied warranties for the associated TI product or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyers and others who are developing systems that incorporate TI products (collectively, "Designers") understand and agree that Designers remain responsible for using their independent analysis, evaluation and judgment in designing their applications and that Designers have full and exclusive responsibility to assure the safety of Designers' applications and compliance of their applications (and of all TI products used in or for Designers' applications) with all applicable regulations, laws and other applicable requirements. Designer represents that, with respect to their applications, Designer has all the necessary expertise to create and implement safeguards that (1) anticipate dangerous consequences of failures, (2) monitor failures and their consequences, and (3) lessen the likelihood of failures that might cause harm and take appropriate actions. Designer agrees that prior to using or distributing any applications that include TI products, Designer will thoroughly test such applications and the functionality of such TI products as used in such applications.

TI's provision of technical, application or other design advice, quality characterization, reliability data or other services or information, including, but not limited to, reference designs and materials relating to evaluation modules, (collectively, "TI Resources") are intended to assist designers who are developing applications that incorporate TI products; by downloading, accessing or using TI Resources in any way, Designer (individually or, if Designer is acting on behalf of a company, Designer's company) agrees to use any particular TI Resource solely for this purpose and subject to the terms of this Notice.

TI's provision of TI Resources does not expand or otherwise alter TI's applicable published warranties or warranty disclaimers for TI products, and no additional obligations or liabilities arise from TI providing such TI Resources. TI reserves the right to make corrections, enhancements, improvements and other changes to its TI Resources. TI has not conducted any testing other than that specifically described in the published documentation for a particular TI Resource.

Designer is authorized to use, copy and modify any individual TI Resource only in connection with the development of applications that include the TI product(s) identified in such TI Resource. NO OTHER LICENSE, EXPRESS OR IMPLIED, BY ESTOPPEL OR OTHERWISE TO ANY OTHER TI INTELLECTUAL PROPERTY RIGHT, AND NO LICENSE TO ANY TECHNOLOGY OR INTELLECTUAL PROPERTY RIGHT OF TI OR ANY THIRD PARTY IS GRANTED HEREIN, including but not limited to any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI products or services are used. Information regarding or referencing third-party products or services does not constitute a license to use such products or services, or a warranty or endorsement thereof. Use of TI Resources may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

TI RESOURCES ARE PROVIDED "AS IS" AND WITH ALL FAULTS. TI DISCLAIMS ALL OTHER WARRANTIES OR REPRESENTATIONS, EXPRESS OR IMPLIED, REGARDING RESOURCES OR USE THEREOF, INCLUDING BUT NOT LIMITED TO ACCURACY OR COMPLETENESS, TITLE, ANY EPIDEMIC FAILURE WARRANTY AND ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE, AND NON-INFRINGEMENT OF ANY THIRD PARTY INTELLECTUAL PROPERTY RIGHTS. TI SHALL NOT BE LIABLE FOR AND SHALL NOT DEFEND OR INDEMNIFY DESIGNER AGAINST ANY CLAIM, INCLUDING BUT NOT LIMITED TO ANY INFRINGEMENT CLAIM THAT RELATES TO OR IS BASED ON ANY COMBINATION OF PRODUCTS EVEN IF DESCRIBED IN TI RESOURCES OR OTHERWISE. IN NO EVENT SHALL TI BE LIABLE FOR ANY ACTUAL, DIRECT, SPECIAL, COLLATERAL, INDIRECT, PUNITIVE, INCIDENTAL, CONSEQUENTIAL OR EXEMPLARY DAMAGES IN CONNECTION WITH OR ARISING OUT OF TI RESOURCES OR USE THEREOF, AND REGARDLESS OF WHETHER TI HAS BEEN ADVISED OF THE POSSIBILITY OF SUCH DAMAGES.

Unless TI has explicitly designated an individual product as meeting the requirements of a particular industry standard (e.g., ISO/TS 16949 and ISO 26262), TI is not responsible for any failure to meet such industry standard requirements.

Where TI specifically promotes products as facilitating functional safety or as compliant with industry functional safety standards, such products are intended to help enable customers to design and create their own applications that meet applicable functional safety standards and requirements. Using products in an application does not by itself establish any safety features in the application. Designers must ensure compliance with safety-related requirements and standards applicable to their applications. Designer may not use any TI products in life-critical medical equipment unless authorized officers of the parties have executed a special contract specifically governing such use. Life-critical medical equipment is medical equipment where failure of such equipment would cause serious bodily injury or death (e.g., life support, pacemakers, defibrillators, heart pumps, neurostimulators, and implantables). Such equipment includes, without limitation, all medical devices identified by the U.S. Food and Drug Administration as Class III devices and equivalent classifications outside the U.S.

TI may expressly designate certain products as completing a particular qualification (e.g., Q100, Military Grade, or Enhanced Product). Designers agree that it has the necessary expertise to select the product with the appropriate qualification designation for their applications and that proper product selection is at Designers' own risk. Designers are solely responsible for compliance with all legal and regulatory requirements in connection with such selection.

Designer will fully indemnify TI and its representatives against any damages, costs, losses, and/or liabilities arising out of Designer's non-compliance with the terms and provisions of this Notice.

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Operational Amplifiers - Op Amps category:

Click to view products by Texas Instruments manufacturer:

Other Similar products are found below:

430227FB LT1678IS8 NCV33202DMR2G NJM324E M38510/13101BPA NTE925 AZV358MTR-G1 AP4310AUMTR-AG1
AZV358MMTR-G1 SCY33178DR2G NCV20034DR2G NTE778S NTE871 NTE937 NJU7057RB1-TE2 SCY6358ADR2G
NJM2904CRB1-TE1 UPC4570G2-E1-A UPC4741G2-E1-A NJM8532RB1-TE1 EL2250CS EL5100IS EL5104IS EL5127CY EL5127CYZ
EL5133IW EL5152IS EL5156IS EL5162IS EL5202IY EL5203IY EL5204IY EL5210CS EL5210CYZ EL5211IYE EL5220CY
EL5223CLZ EL5223CR EL5224ILZ EL5227CLZ EL5227CRZ EL5244CS EL5246CS EL5246CSZ EL5250IY EL5251IS EL5257IS
EL5260IY EL5261IS EL5300IU